

SK6011 300mA Ultra-Low-Noise LDO for RF and Analog Circuits

DESCRIPTION

The SK6011 family of low-dropout (LDO), low-power linear regulators offers very high power supply rejection ratio (PSRR) while maintaining very low quiescent current, suitable for RF applications. The family uses an advanced CMOS process and a PMOSFET pass device to achieve fast start-up, very low noise, excellent transient response, and excellent PSRR performance.

The SK6011 is stable with a 1.0 μ F ceramic output capacitor, and uses a precision voltage reference and feedback loop to achieve a worst-case accuracy of 2% over all load, line, process, and temperature variations. It is fully specified from $T_J = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$ and is offered in a small UTDFN1 \times 1-4, DFN1 \times 1-4 and SOT23-5 package, which is ideal for small form factor portable equipment such as wireless handsets and PDAs.

FEATURES

- Wide Input Voltage Range : 1.9 V to 5.5 V
- Output Voltage : 1.2 V to 4.5 V
- Up to 300 mA Load Current
- Other Output Voltage Options Available on Request
- Very Low IQ: 14 μ A
- Low Dropout: 180 mV @ 3.3 V typical
- Very High PSRR: 90 dB at 1 kHz
- Ultra Low Noise: 10 μ VRMS at 3.3 V output (load = 1 mA)
- Excellent Load/Line Transient Response
- Line Regulation: 0.02%/V typical
- Short-Circuit Current Limit: 80 mA (Current at short mode) typical
- With Auto Discharge

APPLICATIONS

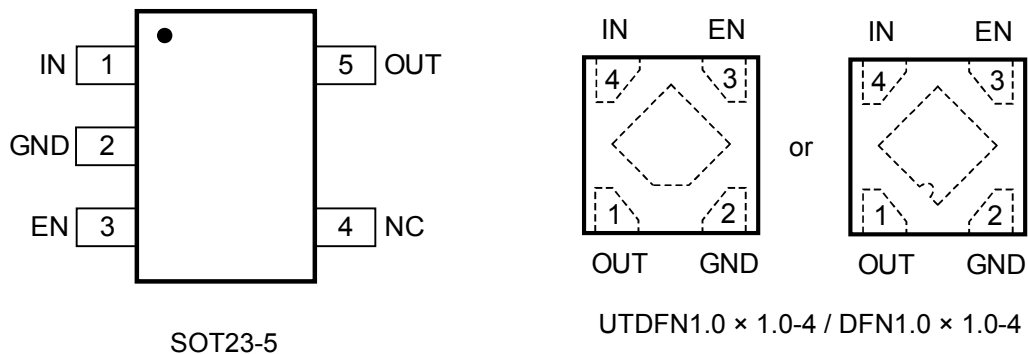
- Smart Phones and Cellular Phones
- PDAs
- MP3/MP4 Player
- Digital Still Cameras
- Portable Instrument

ORDERING INFORMATION

Ordering Number	Package	Packing Option
SK6011UD4-XX	UTDFN1 \times 1-4	Tape and Reel, 10000
SK6011D4-XX	DFN1 \times 1-4	Tape and Reel, 10000
SK6011S5-XX	SOT23-5	Tape and Reel, 3000

*XX: When expressed as 18, the output voltage is 1.8 V; when expressed as 30 the output voltage is 3.0 V.

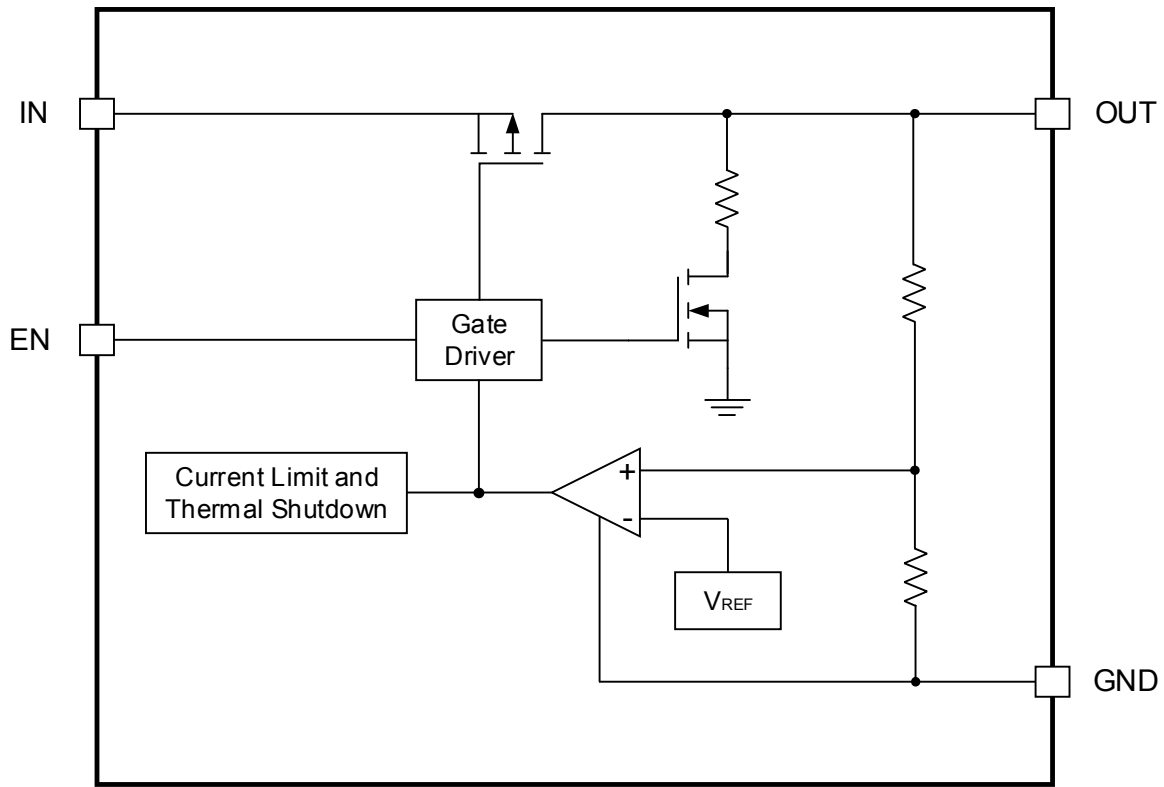
PIN CONFIGURATION (Top View)



PIN DESCRIPTIONS

Pin		Symbol	Description
SOT23-5	UTDFN1×1-4 DFN1×1-4		
1	4	IN	Supply input pin. Must be closely decoupled to GND with a 1 μF or greater ceramic capacitor.
2	2	GND	Ground.
3	3	EN	Enable control input, active high. Do not leave EN floating.
4		NC	No Connection.
5	1	OUT	Output pin. Bypass a 1 μF ceramic capacitor from this pin to ground.

BLOCK DIAGRAM



FUNCTIONAL DESCRIPTION

Input Capacitor

A 1 μF ceramic capacitor is recommended to connect between IN and GND pins to decouple input power supply glitch and noise. The amount of the capacitance may be increased without limit. This input capacitor must be located as close as possible to the device to assure input stability and less noise. For PCB layout, a wide copper trace is required for both IN and GND. The input capacitor should be at least equal to, or greater than, the output capacitor for good load transient performance.

Output Capacitor

An output capacitor is required for the stability of the LDO. The recommended output capacitance is from 1 μF to 10 μF , Equivalent Series Resistance (ESR) is from 5 m Ω to 500 m Ω , and temperature characteristics are X7R or X5R. Higher capacitance values help to improve load/line transient response. The output capacitance may be increased to keep low undershoot/overshoot. Place output capacitor as close as possible to OUT and GND pins. With a reasonable PCB layout, the single 1 μF ceramic output capacitor can be placed up to 10 cm away from the SK6011 device.

ON/OFF Input Operation

The SK6011 EN pin is internally held low by a 1 M Ω resistor to GND. The SK6011 is turned on by setting the EN pin higher than V_{IH} threshold, and is turned off by pulling it lower than V_{IL} threshold. If this feature is not used, the EN pin should be tied to IN pin to keep the regulator output on at all time.

High PSRR and Low Noise

RF circuits such as LNA (low-noise amplifier), up/down-converter, mixer, PLL, VCO, and IF stage, require low noise and high PSRR LDOs. The temperature-compensated crystal oscillator circuit requires very high PSRR at RF power amplifier burst frequency. For instance, minimum 65 dB PSRR at 217 Hz is recommended for the GSM handsets.

In order to provide good audio quality, the audio power supply for hand-free, game, MP3, and multimedia applications in cellular phones, require low-noise and high PSRR at audio frequency range (20 Hz to 20 kHz). The SK6011, with PSRR of 90 dB at 1 kHz, is suitable for most of these applications that require high PSRR and low noise.

Output Automatic Discharge

The SK6011 output employs an internal 60 Ω (typical) pulldown resistance to discharge the output when the EN pin is low, and the device is disabled.

Remote Output Capacitor Placement

The SK6011 requires at least a 1 μ F capacitor at the OUT pin, but there are no strict requirements about the location of the capacitor in regards the OUT pin. In practical designs, the output capacitor may be located up to 10 cm away from the LDO.

Fast Transient Response

Fast transient response LDOs can also extend battery life. TDMA-based cell phone protocols such as Global System for Mobile Communications (GSM) have a transmit/receive duty factor of only 12.5 percent, enabling power savings by putting much of the baseband circuitry into standby mode in between transmit cycles. In baseband circuits, the load often transitions virtually instantaneously from 100 μ A to 100 mA. To meet this load requirement, the LDO must react very quickly without a large voltage drop or overshoot -- a requirement that cannot be met with conventional, general-purpose LDOs.

The SK6011's fast transient response from 0 to 300 mA provides stable voltage supply for fast DSP and GSM chipset with fast changing load.

Low Quiescent Current

Cellular phone baseband internal digital circuits typically operate all the time. That requires LDO stays on at all times. However, in the standby mode, the microprocessor consumes only around 100 ~ 300 μ A. Since the phone stays in standby for the longest percentage of time, using a 14 μ A quiescent current LDO, instead of 100- μ A, saves 88 μ A and can substantially extends the battery standby time.

The SK6011, consuming only 14 μ A quiescent current, provides great power saving in portable and low power applications.

Minimum Operating Input Voltage (V_{IN})

The SK6011 does not include any dedicated UVLO circuitry. The SK6011 internal circuitry is not fully functional until V_{IN} is at least 1.8 V. The output voltage is not regulated until V_{IN} has reached at least the greater of 1.8 V or ($V_{OUT} + V_{DROP}$).

Current Limit Protection

When output current at the OUT pin is higher than current limit threshold or the OUT pin is short-circuit to GND, the current limit protection will be triggered and clamp the output current to approximately 80 mA to prevent over-current and to protect the regulator from damage due to overheating.

Thermal Overload Protection (TSD)

Thermal shutdown disables the output when the junction temperature rises to approximately 155°C which allows the device to cool. When the junction temperature cools to approximately 140°C, the output circuitry enables. Based on power dissipation, thermal resistance, and ambient temperature, the thermal protection circuit may cycle on and off. This thermal cycling limits the dissipation of the regulator and protects it from damage as a result of overheating.

The thermal shutdown circuitry of the SK6011 has been designed to protect against temporary thermal overload conditions. The TSD circuitry was not intended to replace proper heat-sinking. Continuously running the SK6011 device into thermal shutdown may degrade device reliability

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Min	Max	Unit
IN Voltage	V_{IN}	-0.3	6.0	V
Other Pin Voltage		-0.3	$V_{IN} + 0.3$	V
Maximum Load Current		Internal Limited		mA
Operating Junction Temperature	T_{OP}	-40	+125	°C
Storage Temperature	T_{STG}	-65	+150	°C
Lead Temperature(Soldering, 10 sec)	T_L		300	°C

NOTE:

Stresses beyond those listed under “ABSOLUTE MAXIMUM RATINGS” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

CAUTION

This integrated circuit can be damaged by ESD if you don't pay attention to ESD protection. SUNTEK recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

SUNTEK reserves the right to make any change in circuit design, specification or other related things if necessary without notice at any time. Please contact SUNTEK sales office to get the latest datasheet.

ELECTRICAL CHARACTERISTICS

$T_A = +25^\circ\text{C}$, $C_{IN} = 1\ \mu\text{F}$, $C_{OUT} = 1\ \mu\text{F}$, unless otherwise noted.

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
V_{IN}	Input Voltage Range		1.9		5.5	V
ΔV_{OUT}	Output Voltage Tolerance	$V_{IN} = 2.8\ \text{V to } 5.5\ \text{V}$, $I_{OUT} = 1\ \text{mA to } 300\ \text{mA}$	-2		2	% V_{OUT}
	Line Regulation	$V_{IN} = 2.8\ \text{V to } 5.5\ \text{V}$, $I_{OUT} = 1\ \text{mA}$		0.02		%/V
	Load Regulation	$I_{OUT} = 1\ \text{mA to } 300\ \text{mA}$			1	%
I_{LOAD}	Maximum Load Current	$V_{IN} = V_{OUT} + 1\ \text{V}$	300			mA
I_{SHDN}	Input Shutdown Quiescent Current	$V_{EN} = 0\ \text{V}$		0.2	1	μA
I_Q	Input Quiescent Current	$V_{IN} > 1.9\ \text{V}$, $V_{EN} > 1.2\ \text{V}$, $I_{OUT} = 0\ \text{mA}$		14	25	μA
V_{DROP}	Dropout Voltage ⁽¹⁾	$I_{OUT} = 100\ \text{mA}$		50	100	mV
		$I_{OUT} = 300\ \text{mA}$		180	300	mV
I_{LMT}	Output Current Limit	$T_A = 25^\circ\text{C}$	310	500		mA
I_{SC}	Short-Circuit Current Limit	$V_{OUT} = 0\ \text{V}$		80		mA
PSRR	Power Supply Rejection Ratio	$f = 100\ \text{Hz}$, $I_{OUT} = 1\ \text{mA}$		94		dB
		$f = 1\ \text{kHz}$, $I_{OUT} = 1\ \text{mA}$		90		dB
		$f = 10\ \text{kHz}$, $I_{OUT} = 1\ \text{mA}$		84		dB
		$f = 100\ \text{kHz}$, $I_{OUT} = 1\ \text{mA}$		71		dB
		$f = 1\ \text{MHz}$, $I_{OUT} = 1\ \text{mA}$		60		dB
		$f = 100\ \text{Hz}$, $I_{OUT} = 20\ \text{mA}$		84		dB
		$f = 1\ \text{kHz}$, $I_{OUT} = 20\ \text{mA}$		83		dB
		$f = 10\ \text{kHz}$, $I_{OUT} = 20\ \text{mA}$		77		dB
		$f = 100\ \text{kHz}$, $I_{OUT} = 20\ \text{mA}$		60		dB
		$f = 1\ \text{MHz}$, $I_{OUT} = 20\ \text{mA}$		58		dB
e_N	Output Noise Voltage	$BW = 10\ \text{Hz to } 100\ \text{kHz}$, $I_{OUT} = 1\ \text{mA}$		10		μV_{RMS}
		$BW = 10\ \text{Hz to } 100\ \text{kHz}$, $I_{OUT} = 300\ \text{mA}$		6.5		μV_{RMS}
$R_{DISCHARGE}$	Output Discharge Resistance	$V_{EN} < V_{IL}$ (output disable)		60		Ω
V_{IL}	EN Input Logic Low Voltage	$V_{IN} = 1.8\ \text{V to } 5.5\ \text{V}$, V_{EN} falling until the output is disabled			0.4	V
V_{IH}	EN Input Logic High Voltage	$V_{IN} = 1.8\ \text{V to } 5.5\ \text{V}$, V_{EN} rising until the output is enabled	1			V
I_{EN}	EN Input leakage current	$V_{IN} = 5.5\ \text{V}$, $V_{EN} = 0\ \text{V}$		0.01	1	μA
		$V_{IN} = 5.5\ \text{V}$, $V_{EN} = 5.5\ \text{V}$		5.5		μA
T_{SHDN}	Thermal shutdown threshold	$V_{IN} = 2.8\ \text{V}$, T_J rising		155		$^\circ\text{C}$
T_{HYS}	Thermal shutdown hysteresis	$V_{IN} = 2.8\ \text{V}$, T_J falling from shutdown		15		$^\circ\text{C}$

NOTE:

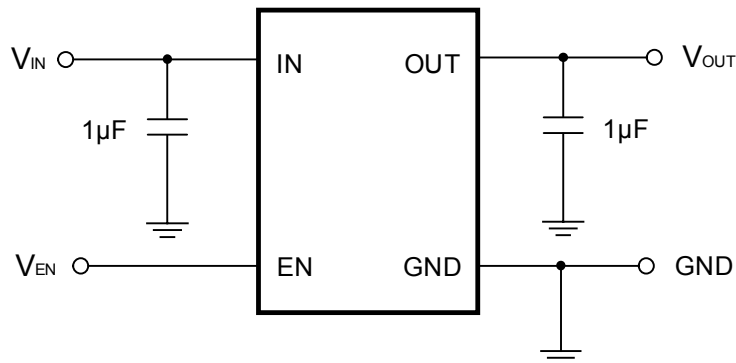
(1) V_{DROP} is measured for devices with $V_{OUT} \geq 1.5\ \text{V}$.

ELECTRICAL CHARACTERISTICS (Continued)

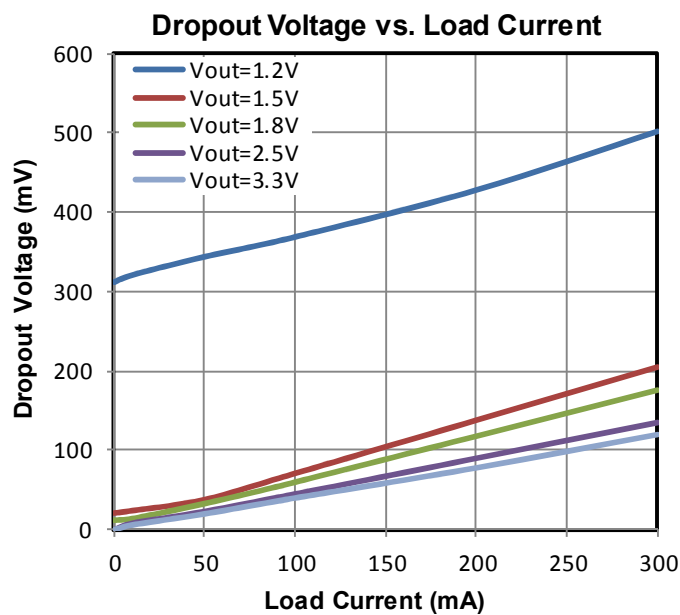
$T_A = +25^\circ\text{C}$, $C_{IN} = 1\ \mu\text{F}$, $C_{OUT} = 1\ \mu\text{F}$, unless otherwise noted.

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
ΔV_{OUT}	Line transient	$V_{IN} = (V_{OUT(NOM)} + 1\ \text{V})$ to $(V_{OUT(NOM)} + 1.6\ \text{V})$ in $10\ \mu\text{s}$		10		mV
		$V_{IN} = (V_{OUT(NOM)} + 1.6\ \text{V})$ to $(V_{OUT(NOM)} + 1\ \text{V})$ in $10\ \mu\text{s}$		10		mV
	Load transient	$I_{OUT} = 1\ \text{mA}$ to $300\ \text{mA}$ in $10\ \mu\text{s}$		20		mV
		$I_{OUT} = 300\ \text{mA}$ to $1\ \text{mA}$ in $10\ \mu\text{s}$		20		mV
Overshoot	Overshoot on start-up	Stated as percentage of $V_{OUT(NOM)}$			5	%
$T_{D(ON)}$	Output Turn-on Delay Time	From $V_{EN} > V_{IH}$ to $V_{OUT} = 95\%$ of $V_{OUT(NOM)}$		150	250	μs

APPLICATION CIRCUITS

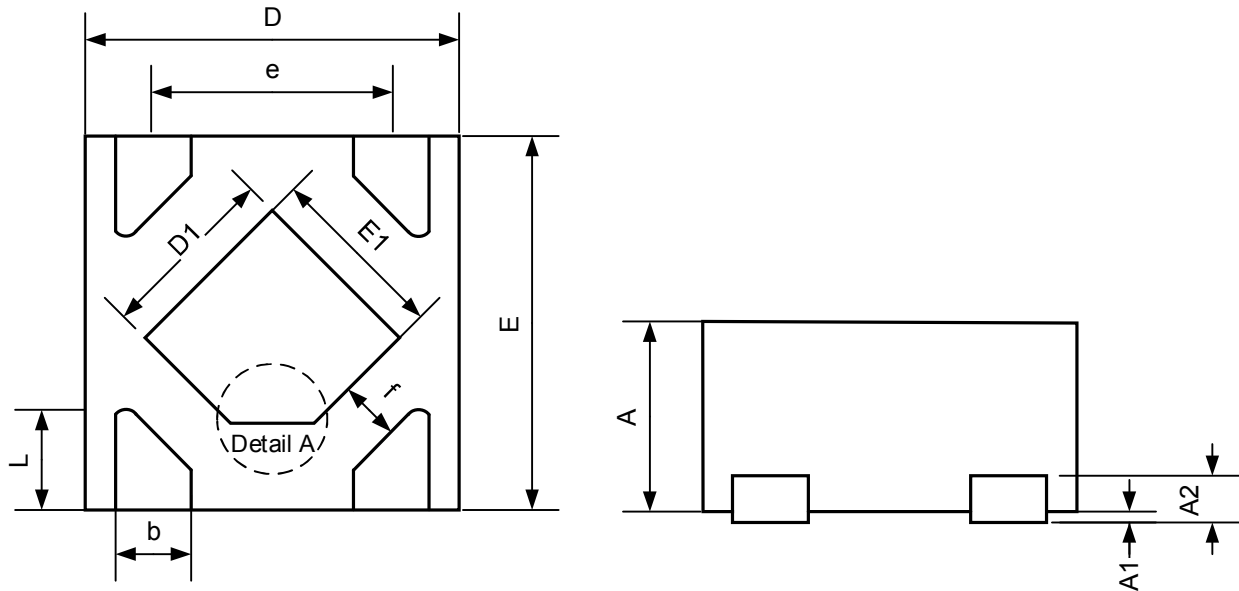


TYPICAL PERFORMANCE CHARACTERISTICS



PACKAGE OUTLINE

UTDFN1.0 × 1.0-4



Detail A:

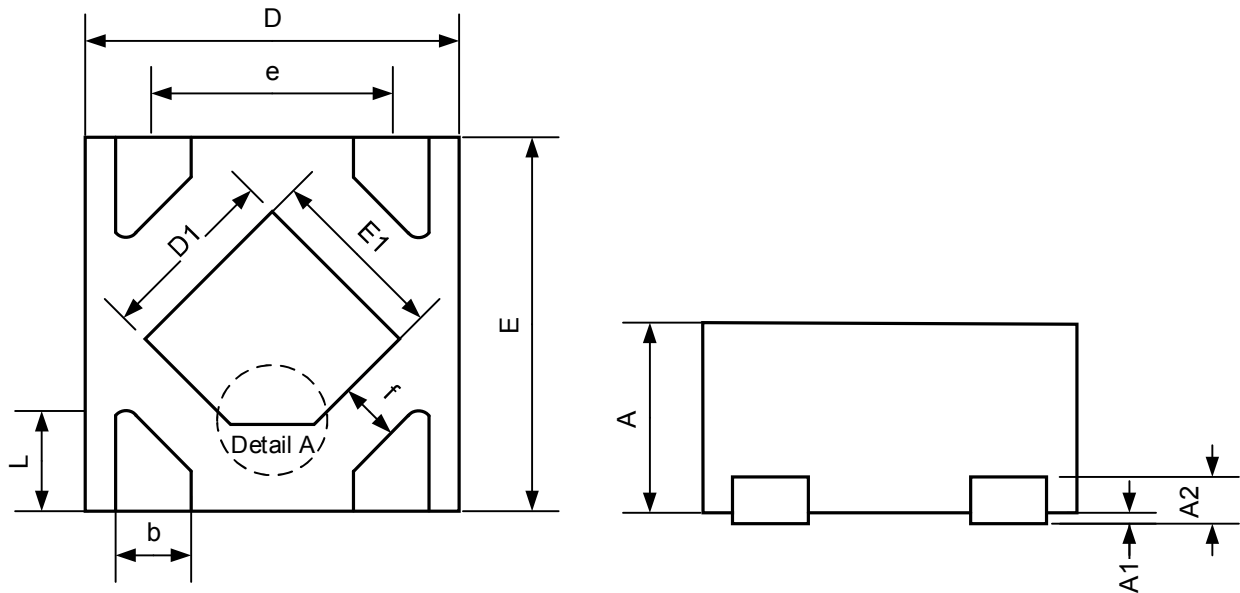


Note: Detail A has two kinds of shapes

Symbol	Dimensions In Millimeters		
	Min	Mod	Max
A	0.370	0.400	0.430
A1	0.000	0.020	0.050
A2	0.100REF		
D	0.950	1.000	1.050
D1	0.430	0.480	0.530
E	0.950	1.000	1.050
E1	0.430	0.480	0.530
b	0.170	0.220	0.270
e	0.650BSC		
f	0.190	0.195	0.200
L	0.200	0.250	0.300

PACKAGE OUTLINE

DFN1.0 × 1.0-4



Detail A:

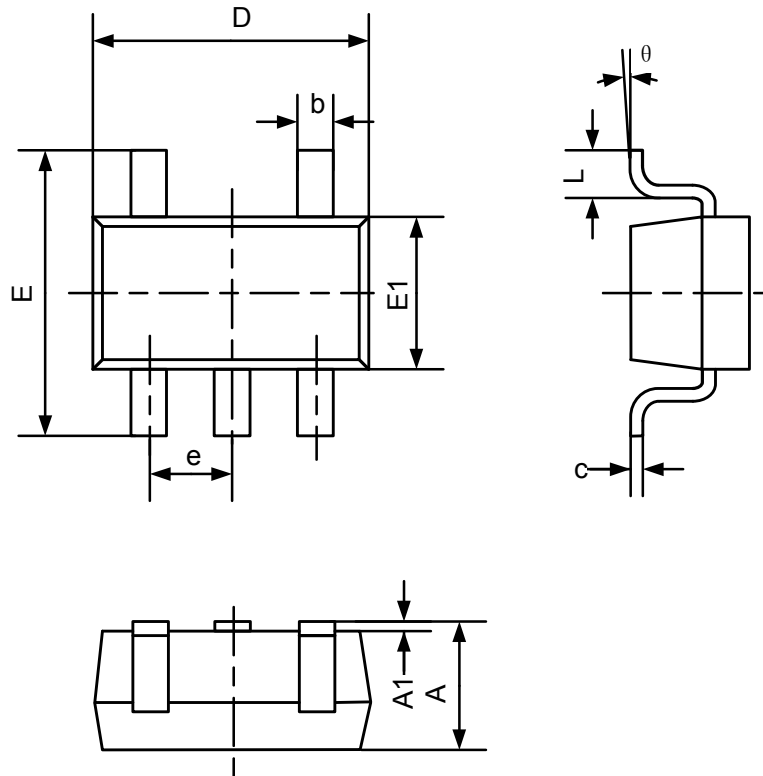


Note: Detail A has two kinds of shapes

Symbol	Dimensions In Millimeters		
	Min	Mod	Max
A	0.450	0.500	0.550
A1	0.000	0.025	0.050
A2	0.125REF		
D	0.950	1.000	1.050
D1	0.380	0.480	0.580
E	0.950	1.000	1.050
E1	0.380	0.480	0.580
b	0.150	0.200	0.250
e	0.650BSC		
f	0.190	0.195	0.200
L	0.150	0.250	0.350

PACKAGE OUTLINE

SOT23-5



Symbol	Dimensions In Millimeters	
	Min	Max
A	0.700	1.250
A1	0.000	0.100
b	0.300	0.500
c	0.100	0.200
D	2.820	3.020
E	2.650	2.950
E1	1.500	1.700
e	0.950BSC	
L	0.300	0.600
θ	0°	8°

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